

# **Excellent Integrated System Limited**

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Vishay Semiconductor/Diodes Division VS-20CWT10FNTR

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## VS-20CUT10, VS-20CWT10FN

Vishay Semiconductors

## High Performance Schottky Generation 5.0, 2 x 10 A





I-PAK (TO-251AA) Base common cathode

4

62

Common

cathode

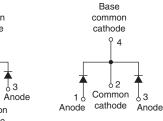
**VS-20CUT10** 

71

Anode

l 3

D-PAK (TO-252AA)



VS-20CWT10FN

PRODUCT SUMMARY					
Package	D-PAK (TO-252AA), I-PAK (TO-251AA)				
I <sub>F(AV)</sub>	2 x 10 A				
V <sub>R</sub>	100 V				
V <sub>F</sub> at I <sub>F</sub>	0.66 V				
I <sub>RM</sub> max.	4 mA at 125 °C				
T <sub>J</sub> max.	175 °C				
Diode variation	Common cathode				
E <sub>AS</sub>	54 mJ				

#### **FEATURES**

- 175 °C high performance Schottky diode
- Very low forward voltage drop
- Extremely low reverse leakage
- RoHS Optimized V<sub>F</sub> vs. I<sub>R</sub> trade off for high efficiency COMPLIANT
- · Increased ruggedness for reverse avalanche capability
- RBSOA available
- Negligible switching losses
- Submicron trench technology
- Compliant to RoHS Directive 2002/95/EC

#### **APPLICATIONS**

- High efficiency SMPS
- High frequency switching
- Output rectification
- Reverse battery protection
- Freewheeling
- DC/DC systems
- · Increased power density systems

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
V <sub>RRM</sub>		100	V				
V <sub>F</sub>	10 Apk, T <sub>J</sub> = 125 °C (typical, per leg)	0.615	V				
TJ	Range	- 55 to 175	C°				

VOLTAGE RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VS-20CUT10 VS-20CWT10FN	UNITS
Maximum DC reverse voltage	V <sub>R</sub>	T <sub>J</sub> = 25 °C	100	V

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1





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## VS-20CUT10, VS-20CWT10FN

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ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONE	DITIONS	VALUES	UNITS		
Maximum average per leg				50 % duty cycle at T <sub>C</sub> = 159 °C, rectangular waveform		10	٨
forward current per device	I <sub>F(AV)</sub>	30% duty cycle at $1C = 139%$	, rectangular wavelonn	20	A		
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	610	А		
non-repetitive surge current per leg	IFSM	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	110	~		
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 3 A, L = 12 mH		54	mJ		
Repetitive avalanche current per leg	I <sub>AR</sub>	Limited by frequency of operation and time pulse duration so that $T_J < T_J$ max. $I_{AS}$ at $T_J$ max. as a function of time pulse (see fig. 8)		I <sub>AS</sub> at T <sub>J</sub> max.	A		

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	TYP.	MAX.	UNITS	
		10 A	т ос оо	0.735	0.810	v	
Forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	20 A	T <sub>J</sub> = 25 °C	0.840	0.890		
	V FM (*)	10 A	- T <sub>J</sub> = 125 °C	0.615	0.660	v	
		20 A		0.730	0.770		
Poverse leakage ourrent per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C		-	50	μA	
Reverse leakage current per leg		T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	-	4	mA	
Junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range	100 kHz to 1 MHz), 25 °C	400	-	pF	
Series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 mm	8.0	-	nH		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	-	10 000	V/µs		

Note

 $^{(1)}$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 175	°C	
Maximum thermal resistance, junction to case per leg	D		2		
Maximum thermal resistance, junction to case per device	R <sub>thJC</sub>	DC operation	1	°C/W	
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>		0.3		
Approximate weight			0.3	g	
Approximate weight			0.01	oz.	
		Case style I-PAK		JT10	
Marking device		Case style D-PAK	20CW	T10FN	

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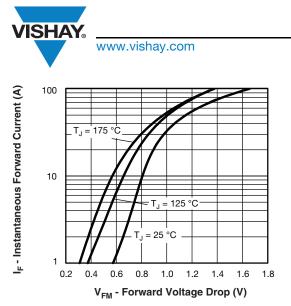
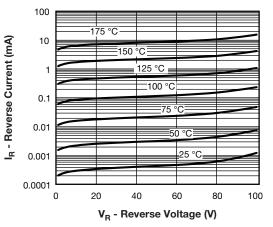
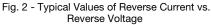


Fig. 1 - Maximum Forward Voltage Drop Characteristics



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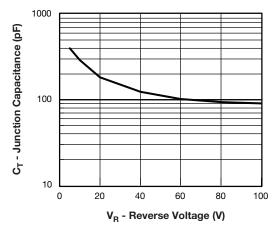
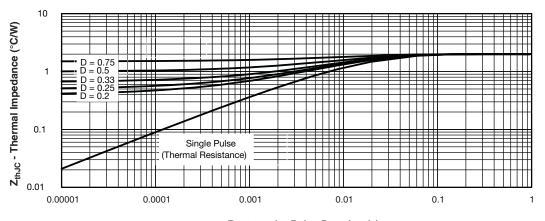


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



t<sub>1</sub> - Rectangular Pulse Duration (s)

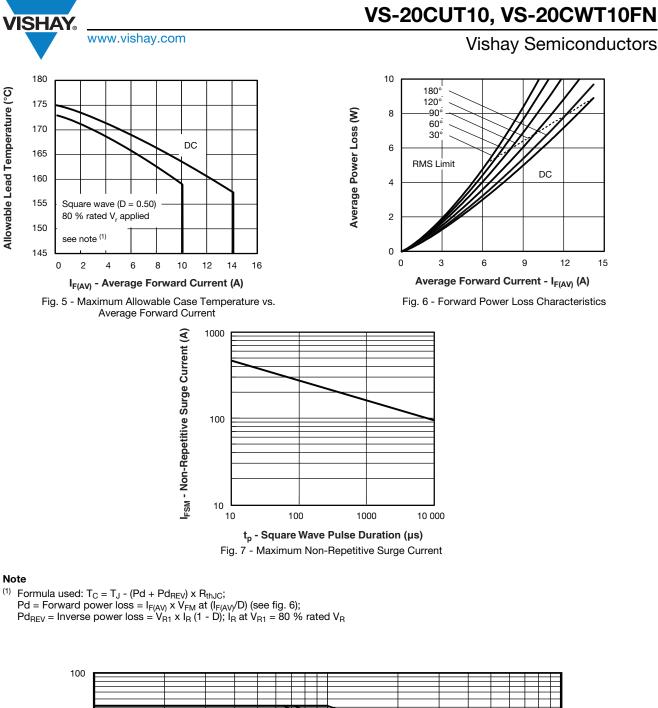
Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

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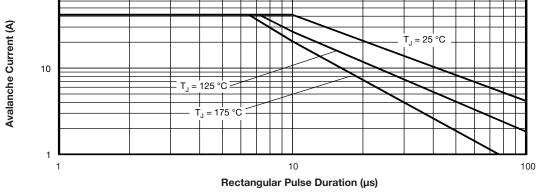
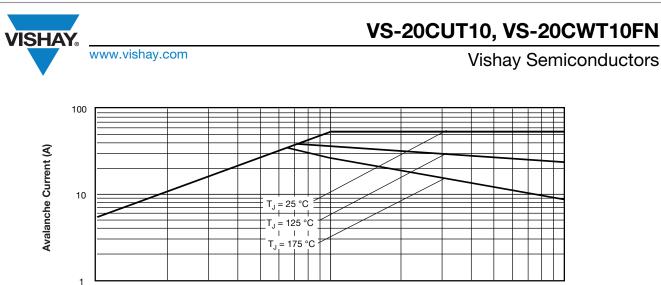


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

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#### 10 Rectangular Pulse Duration (μs)

Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)

#### **ORDERING INFORMATION TABLE**

Device code	VS-	20	с	U	т	10	FN	TRL
	1	2	3	4	5	6	7	8
	1 .	- Vis	hay Ser	nicondu	ctors pro	oduct		
	2	- Cu	rrent rati	ing (20 A	4)			
	3	- Cir	cuit conf	iguratio	n:			
		C =	Comm	on catho	de			
	4	- Pa	ckage:					
		۰U	= I-PAK	ζ.				
		• W	' = D-PA	λK				
	5	- T=	Trench					
	6	- Vol	tage rat	ing (10 =	= 100 V	)		
	7	то	-252AA	(D-PAK	)			
	8	- D-F	PAK, I-P	AK:				
		No	ne = Tul	be (75 p	ieces)			
		D-F	PAK only	/:				
		• TI	R = Tap	e and re	el			
		• TI	RL = Ta	pe and r	eel (left	oriente	d)	
		• TI	RR = Ta	pe and i	reel (rig	ht orien	ted)	

LINKS TO RELATED DOCUMENTS					
Dimensions	I-PAK (TO-251AA)	www.vishay.com/doc?95024			
Dimensions	D-PAK (TO-252AA)	www.vishay.com/doc?95448			
Part marking information	I-PAK (TO-251AA)	www.vishay.com/doc?95025			
	D-PAK (TO-252AA)	www.vishay.com/doc?95059			
Packaging information		www.vishay.com/doc?95033			
SPICE model		www.vishay.com/doc?95041			

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100

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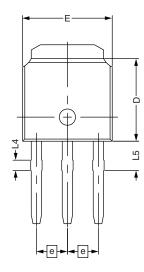


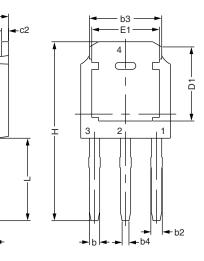
### **Outline Dimensions**

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I-PAK - S

#### DIMENSIONS FOR I-PAK - S in millimeters





SYMBOL	DIMENSIONAL REQUIREMENTS					
STIVIDOL	MIN.	NOM.	MAX.			
E	6.40	6.60	6.70			
L	3.98	4.13	4.28			
L4	0.66	0.76	0.86			
L5	1.96	2.16	2.36			
D	6.00	6.10	6.20			
Н	11.05	11.25	11.45			
b	0.64	0.76	0.88			
b2	0.77	0.84	1.14			
b3	5.21	5.34	5.46			
b4	0.41	0.51	0.61			
е		2.286 BSC				
A	2.20	2.30	2.38			
с	0.40	0.50	0.60			
c2	0.40	0.50	0.60			
D1	5.30	-	-			
E1	4.40	-	-			

с

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